#### **TELEFUNKEN Semiconductors**

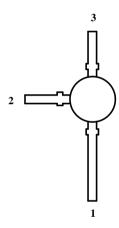
## Silicon NPN Planar RF Transistor

#### **Applications**

RF-amplifier up to GHz range specially for wide band antenna amplifier.

#### **Features**

- High power gain
- Low noise figure
- High transition frequency



BFR90 Marking Plastic case (~TO 50) 1= Collector; 2= Base; 3= Emitter

## **Absolute Maximum Ratings**

Parameters	Symbol	Value	Unit
Collector-base voltage	$V_{\mathrm{CBO}}$	20	V
Collector-emitter voltage	V <sub>CEO</sub>	15	V
Emitter-base voltage	V <sub>EBO</sub>	2	V
Collector current	I <sub>C</sub>	30	mA
Total power dissipation $T_{amb} \le 60^{\circ}C$	P <sub>tot</sub>	300	mW
Junction temperature	Tj	150	°C
Storage temperature range	T <sub>stg</sub>	-65 to +150	°C

#### **Maximum Thermal Resistance**

Parameters	Symbol	Value	Unit
Junction ambient	$R_{thJA}$	300	K/W

## **BFR 90**

#### **Electrical DC Characteristics**

 $T_j = 25$ °C, unless otherwise specified

Parameters / Test Conditions	Symbol	Min.	Тур.	Max.	Unit
Collector cut-off current $V_{CB} = 20 \text{ V}, I_E = 0 \text{ A}$	I <sub>CBO</sub>			50	nA
Collector-base breakdown voltage $I_C = 10 \mu A$	V <sub>(BR)CBO</sub>	20			V
Collector-emitter breakdown voltage $I_C = 2 \text{ mA}$	V <sub>(BR)CEO</sub>	15			V
Emitter-base breakdown voltage $I_E = 10 \; \mu A$	V <sub>(BR)EBO</sub>	2			V
DC forward current transfer ratio $I_C = 14 \text{ mA}, V_{CE} = 10 \text{ V}$	$h_{ m FE}$	25	50		mA

#### **Electrical AC Characteristics**

 $T_{amb}=25^{\circ}\mathrm{C}$ 

Parameters / Test Conditions	Symbol	Min.	Тур.	Max.	Unit
Transition frequency $I_C = 14 \text{ mA}, V_{CE} = 10 \text{ V}, f = 500 \text{ MHz}$	$\mathrm{f}_{\mathrm{T}}$		5		GHz
Collector-emitter capacitance $V_{CE} = 10 \text{ V}, f = 1 \text{ MHz}$	$C_{CE}$		0.27		pF
Collector-base capacitance $V_{CB} = 10 \text{ V}, f = 1 \text{ MHz}$	$C_{CB}$		0.36		pF
Emitter-base capacitance $V_{EB} = 0.5 \text{ V}, f = 1 \text{ MHz}$	$C_{\mathrm{EB}}$		1.3		pF
Noise figure $I_C = 2$ mA, $V_{CE} = 10$ V, $f = 500$ MHz, $Z_G = 50$ $\Omega$	$F_{e}$		2.2		dB
Power gain $I_C = 14 \text{ mA}, V_{CE} = 10 \text{ V}, Z_L = Z_{Lopt}, \\ f = 500 \text{ MHz} \\ f = 800 \text{ MHz}$	$G_{ m pe} \ G_{ m pe}$		19.5 14		dB dB
$ \begin{array}{c} Linear \ output \ voltage-two \ tone \ intermodulation \ test \\ I_C = 14 \ mA, \ V_{CE} = 10 \ V, \ d_{IM} = 60 \ dB, \\ Z_G = Z_L = 50 \ \Omega, \ f_1 = 806 \ MHz, \ f_2 = 810 \ MHz \end{array} $	$V_1 = V_2$		100		mV
Third order intercept point $I_C = 14$ mA, $V_{CE} = 10$ V, $f = 800$ MHz	IP <sub>3</sub>		23		dBm

# **TEMIC**

#### **Common Source S-Parameters**

				S <sub>11</sub>		S <sub>21</sub>		S	S <sub>12</sub>		S <sub>22</sub>	
V <sub>CE</sub> /V	I <sub>C</sub> /mA	f/MHz	LIN MAG	ANG	LIN MAG	ANG	LIN MAG	ANG	LIN MAG	ANG		
				deg		deg		deg		deg		
		100	0.84	-25.7	6.21	157.1	0.02	74.8	0.96	-8.3		
		300	0.61	-68.0	4.69	123.8	0.05	56.2	0.84	-18.4		
		500	0.42	-101.2	3.57	102.1	0.07	49.3	0.75	-22.7		
		800	0.28	-147.9	2.53	80.4	0.08	48.1	0.69	-27.8		
	2	1000	0.26	-177.6	2.14	69.5	0.09	50.0	0.67	-31.6		
		1200	0.27	156.2	1.84	59.0	0.11	51.9	0.65	-35.6		
		1500	0.32	127.9	1.54	46.0	0.13	54.1	0.62	-41.9		
		1800	0.39	109.1	1.34	34.2	0.15	55.0	0.59	-48.8		
		2000	0.43	98.7	1.24	27.3	0.18	54.2	0.57	-53.8		
		100	0.67	-36.6	12.62	146.6	0.02	71.9	0.91	-13.0		
		300	0.36	-83.1	7.54	110.1	0.04	60.7	0.72	-20.7		
		500	0.21	-116.9	5.07	91.8	0.06	60.6	0.65	-22.2		
		800	0.13	-173.7	3.37	74.5	0.08	61.0	0.61	-26.3		
	5	1000	0.14	153.1	2.78	65.5	0.10	60.5	0.59	-29.8		
		1200	0.17	130.1	2.37	56.7	0.12	59.0	0.57	-33.6		
		1500	0.23	110.4	1.97	45.3	0.15	56.1	0.54	-39.7		
		1800	0.29	97.7	1.71	34.6	0.18	53.1	0.51	-45.7		
10		2000	0.33	91.2	1.58	28.0	0.20	50.3	0.49	-50.0		
10		100	0.49	-47.6	18.87	135.7	0.02	71.4	0.83	-16.8		
		300	0.19	-93.8	9.12	101.1	0.04	68.0	0.63	-19.6		
		500	0.09	-133.4	5.82	86.1	0.06	68.4	0.58	-20.2		
		800	0.07	151.2	3.77	71.2	0.09	66.5	0.56	-24.4		
	10	1000	0.10	124.5	3.09	63.3	0.11	64.3	0.54	-28.2		
		1200	0.14	109.4	2.63	55.2	0.13	61.4	0.52	-32.2		
		1500	0.19	98.6	2.17	44.7	0.16	56.9	0.49	-38.0		
		1800	0.26	90.8	1.89	34.6	0.20	52.4	0.46	-44.1		
		2000	0.29	86.0	1.75	28.3	0.22	48.9	0.44	-48.0		
		100	0.39	-53.4	21.53	130.3	0.01	72.2	0.79	-17.8		
		300	0.13	-98.6	9.58	97.8	0.04	71.0	0.60	-18.5		
		500	0.06	-146.3	6.02	84.0	0.06	70.7	0.57	-19.2		
		800	0.07	131.1	3.89	70.0	0.09	67.8	0.55	-23.7		
	14	1000	0.10	113.4	3.18	62.4	0.11	65.3	0.53	-27.4		
		1200	0.13	103.2	2.70	54.7	0.14	62.0	0.51	-31.5		
		1500	0.19	94.2	2.23	44.3	0.17	57.0	0.48	-37.4		
		1800	0.24	89.1	1.93	34.2	0.20	52.3	0.45	-43.3		
		2000	0.29	85.3	1.79	28.13	0.22	48.6	0.43	-47.3		
		100	0.65	-39.9	12.44	145.23	0.02	70.3	0.88	-16.2		
		300	0.35	-91.8	7.26	108.30	0.05	58.7	0.65	-25.4		
		500	0.22	-130.4	4.85	90.23	0.07	58.5	0.57	-26.9		
		800	0.16	177.4	3.22	72.60	0.10	58.2	0.52	-30.6		
5	5	1000	0.18	150.9	2.66	63.49	0.12	57.3	0.50	-34.5		
		1200	0.21	131.6	2.28	54.46	0.14	55.5	0.47	-38.6		
		1500	0.27	112.7	1.89	42.86	0.18	51.9	0.44	-45.2		
		1800	0.33	100.1	1.65	31.82	0.21	48.2	0.40	-52.1		
		2000	0.37	92.8	1.53	25.204	0.24	45.0	0.38	-56.9		

#### **Common Source S-Parameters**

			S <sub>11</sub>		S <sub>21</sub>		S <sub>12</sub>		S <sub>22</sub>	
V <sub>CE</sub> /V	I <sub>C</sub> /mA	f/MHz	LIN MAG	ANG	LIN MAG	ANG	LIN MAG	ANG	LIN MAG	ANG
			11110	deg	11110	deg	11110	deg	11110	deg
		100	0.82	-27.87	6.31	155.8	0.03	73.8	0.95	-10.2
		300	0.59	-72.7	4.66	121.6	0.06	54.0	0.80	-22.1
		500	0.41	-107.7	3.49	99.9	0.08	46.7	0.70	-27.0
		800	0.30	-154.9	2.474	78.0	0.10	44.9	0.63	-32.3
	2	1000	0.29	176.7	2.08	66.9	0.11	46.2	0.60	-36.3
	_	1200	0.30	153.2	1.80	56.4	0.12	47.6	0.57	-40.6
		1500	0.35	126.8	1.50	43.1	0.15	48.9	0.54	-47.6
		1800	0.41	108.7	1.32	31.2	0.18	49.2	0.50	-55.5
		2000	0.45	99.1	1.22	24.4	0.20	48.0	0.48	-61.1
		100	0.18	-87.0	24.23	118.5	0.01	76.0	0.64	-23.6
		300	0.10	-163.4	9.42	91.4	0.04	75.5	0.48	-19.7
		500	0.11	157.7	5.83	79.4	0.07	73.0	0.45	-20.4
		800	0.14	127.7	3.73	65.9	0.11	67.9	0.43	-25.3
	30	1000	0.17	117.0	3.05	58.5	0.14	64.1	0.42	-29.8
		1200	0.20	108.4	2.59	50.7	0.16	59.9	0.40	-34.4
		1500	0.25	100.0	2.14	40.2	0.20	53.9	0.36	-40.8
		1800	0.31	93.2	1.86	29.9	0.23	48.1	0.33	-47.1
_		2000	0.35	88.4	1.71	23.8	0.26	43.9	0.30	-51.6
5		100	0.26	-71.1	22.95	123.4	0.01	72.4	0.68	-23.9
		300	0.11	-140.3	9.39	93.8	0.04	73.2	0.49	-22.0
		500	0.09	169.9	5.84	81.1	0.07	71.5	0.46	-22.0
	20	800	0.13	131.1	3.75	67.3	0.11	66.9	0.43	-26.7
		1000	0.15	117.8	3.07	59.7	0.14	63.3	0.42	-31.0
		1200	0.18	109.5	2.62	51.7	0.16	59.3	0.39	-35.4
		1500	0.24	99.5	2.16	41.1	0.20	53.3	0.36	-41.8
		1800	0.30	93.1	1.87	30.9	0.24	47.7	0.32	-48.1
		2000	0.33	87.9	1.73	24.8	0.26	43.4	0.30	-52.4
		100	0.45	-54.6	18.55	133.7	0.02	70.4	0.79	-21.5
		300	0.19	-112.5	8.73	99.4	0.04	66.6	0.55	-24.7
		500	0.12	-156.4	5.54	84.5	0.07	66.8	0.49	-24.9
		800	0.12	148.7	3.60	69.5	0.11	64.0	0.46	-28.7
	10	1000	0.15	129.3	2.96	61.3	0.13	61.4	0.44	-32.8
		1200	0.18	117.0	2.51	53.0	0.16	58.0	0.42	-37.1
		1500	0.24	104.4	2.08	42.1	0.19	52.8	0.38	-43.5
		1800	0.30	94.9	1.82	31.8	0.23	47.7	0.35	<del>-4</del> 9.9
		2000	0.34	89.5	1.67	25.44	0.25	43.7	0.32	-54.5
	14	100	0.35	-62.6	20.95	128.4	0.02	71.4	0.73	-23.2
		300	0.14	-124.4	9.11	96.3	0.04	70.1	0.51	-23.7
		500	0.10	-173.0	5.71	82.7	0.07	69.3	0.47	-23.7
		800	0.12	138.3	3.70	68.2	0.11	65.5	0.44	-27.7
		1000	0.15	123.3	3.03	60.4	0.13	62.5	0.42	-32.1
		1200	0.18	113.2	2.58	52.3	0.16	58.7	0.40	-36.5
		1500	0.24	101.6	2.13	41.7	0.20	52.8	0.36	-42.9
		1800	0.30	93.2	1.85	31.4	0.23	47.4	0.33	<del>-49.2</del>
		2000	0.33	88.4	1.72	25.0	0.26	43.3	0.30	-53.6

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#### **TELEFUNKEN Semiconductors**

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